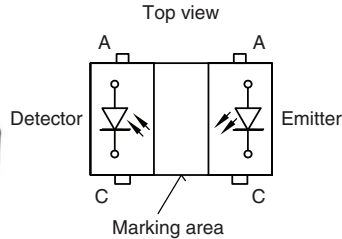


Reflective Optical Sensor with PIN Photodiode Output



FEATURES

- Package type: surface mount
- Detector type: pin photodiode
- Dimensions (L x W x H in mm): 6 x 4.3 x 3.75
- Peak operating distance: 6 mm
- Operating range within > 20 % relative collector current: 2 mm to 25 mm
- Typical output current under test: $I_{ra} > 0.11 \mu A$
- Daylight blocking filter
- High linearity
- Emitter wavelength: 940 nm
- Lead (Pb)-free soldering released
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

DESCRIPTION

The TCND5000 is a reflective sensor that includes an infrared emitter and pin photodiode in a surface mount package which blocks visible light.

APPLICATIONS

- Proximity sensor
- Object sensor
- Motion sensor
- Touch key

PRODUCT SUMMARY

PART NUMBER	DISTANCE FOR MAXIMUM CTR _{rel} (1) (mm)	DISTANCE RANGE FOR RELATIVE I _{out} > 20 % (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (2) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED
TCND5000	6	2 to 25	0.15	Yes

Notes

- (1) CTR: current transference ratio, I_{out}/I_{in}
 (2) Conditions like in table basic characteristics/sensors

ORDERING INFORMATION

ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS
TCND5000	Tape and reel	MOQ: 2000 pcs, 2000 pcs/reel	Drypack

Note

- (1) MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (1)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT (EMITTER)				
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	$t_p = 50 \mu s, t = 2 ms, T_{amb} = 25 \text{ }^\circ C, T_{amb} \leq 25 \text{ }^\circ C$	I_{FM}	500	mA
Power dissipation		P_V	190	mW
Junction temperature		T_j	100	$^\circ C$

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
OUTPUT (DETECTOR)				
Reverse voltage		V_R	60	V
Power dissipation		P_V	75	mW
Junction temperature		T_j	100	°C
SENSOR				
Ambient temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	Acc. fig. 14	T_{sd}	260	°C

Note

(1) $T_{amb} = 25\text{ °C}$, unless otherwise specified

ABSOLUTE MAXIMUM RATINGS

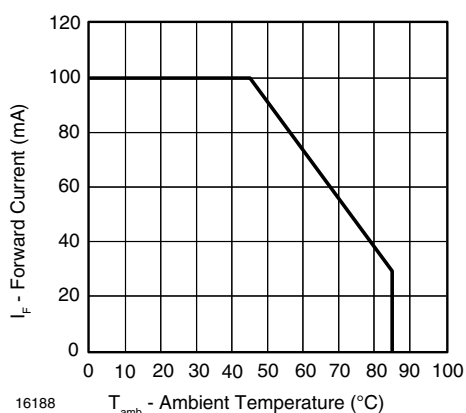


Fig. 1 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT (EMITTER) (2)						
Forward voltage	$I_F = 50\text{ mA}$, $t_p = 20\text{ ms}$	V_F		1.2	1.5	V
Temperature coefficient of V_F	$I_F = 1\text{ mA}$	TK_{V_F}		- 1.3		mV/K
Reverse current	$V_R = 5\text{ V}$	I_R			10	μA
Junction capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0\text{ lx}$	C_j		25		pF
Radiant intensity	$I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$	I_e		7	75	mW/sr
Angle of half intensity		ϕ		± 12		deg
Peak wavelength	$I_F = 100\text{ mA}$	λ_p	930	940		nm
Spectral bandwidth	$I_F = 100\text{ mA}$	$\Delta\lambda$		50		nm
Temperature coefficient of λ_p	$I_F = 100\text{ mA}$	TK_{λ_p}		0.2		nm/K
Rise time	$I_F = 100\text{ mA}$	t_r		800		ns
Fall time	$I_F = 100\text{ mA}$	t_f		800		ns
Virtual source diameter	Method: 63 % encircled energy	d		1.2		mm

BASIC CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
OUTPUT (DETECTOR) (3)						
Forward voltage	$I_F = 50 \text{ mA}$	V_F		1	1.3	V
Breakdown voltage	$I_R = 100 \text{ }\mu\text{A}$	V_{BR}	60			V
Reverse dark current	$V_R = 10 \text{ V}, E = 0 \text{ lx}$	I_{ro}		1	10	nA
Diode capacitance	$V_R = 5 \text{ V}, f = 1 \text{ MHz}, E = 0 \text{ lx}$	C_D		1.8		pF
Reverse light current	$E_e = 1 \text{ mW/cm}^2,$ $\lambda = 950 \text{ nm}, V_R = 5 \text{ V}$	I_{ra}		12		μA
Temperature coefficient of I_{ra}	$\lambda = 870 \text{ nm}, V_R = 5 \text{ V}$	TK_{ira}		0.2		%/K
Angle of half intensity		ϕ		± 15		deg
Wavelength of peak sensitivity		λ_p		930		nm
Range of spectral bandwidth		$\lambda_{0.5}$		840 to 1050		nm
SENSOR						
Reverse Light Current	$V_R = 2.5 \text{ V}, I_F = 20 \text{ mA}, D = 30 \text{ mm},$ reflective mode: see figure 2	I_{ra}	110			nA

Note

- (1) $T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified
 (2) See figures 2 to 8 accordingly
 (3) See figures 9 to 12 accordingly

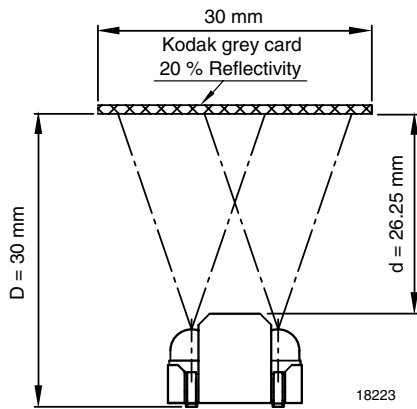
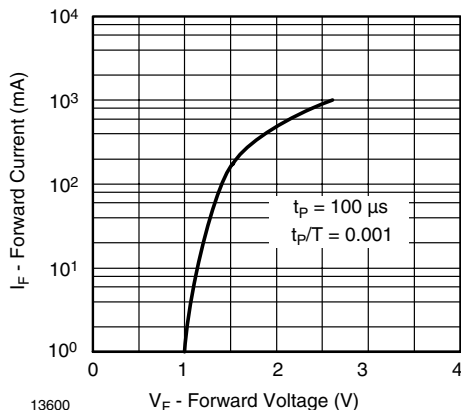
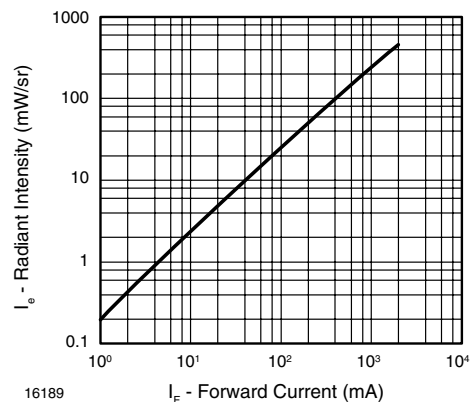


Fig. 2 - Test Circuit

BASIC CHARACTERISTICS
 $T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified


13600

Fig. 3 - Forward Current vs. Forward Voltage



16189

Fig. 4 - Radiant Intensity vs. Forward Current

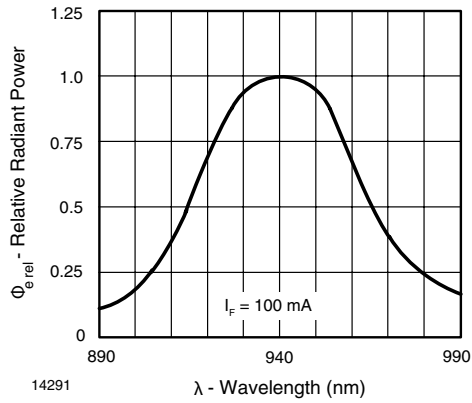


Fig. 5 - Relative Radiant Power vs. Wavelength

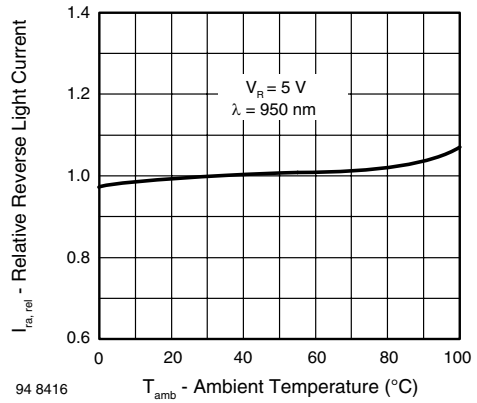


Fig. 8 - Relative Reverse Light Current vs. Ambient Temperature

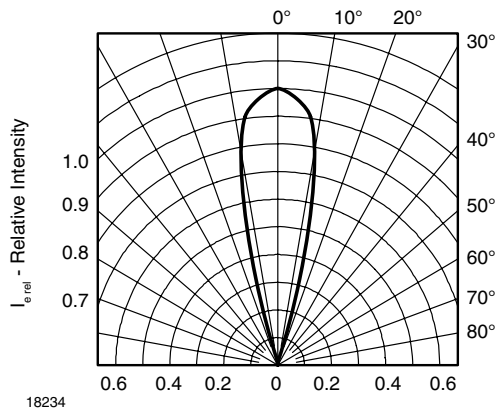


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

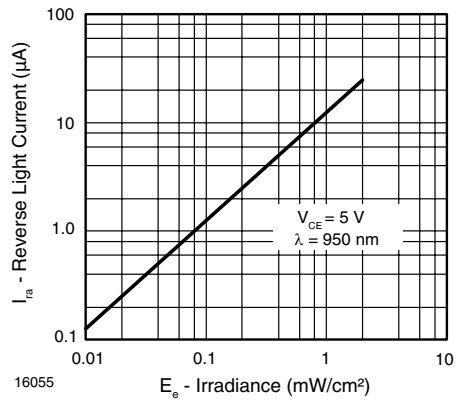


Fig. 9 - Reverse Light Current vs. Irradiance

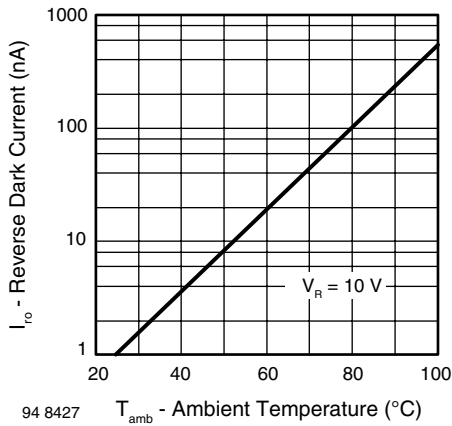


Fig. 7 - Reverse Dark Current vs. Ambient Temperature

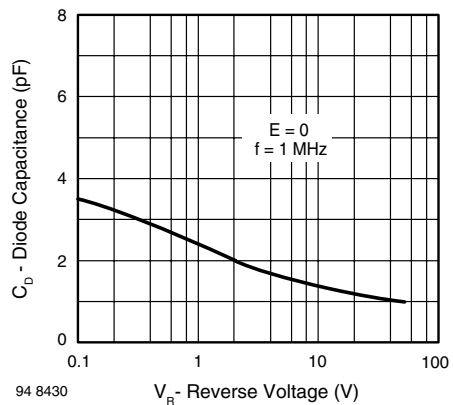


Fig. 10 - Diode Capacitance vs. Reverse Voltage

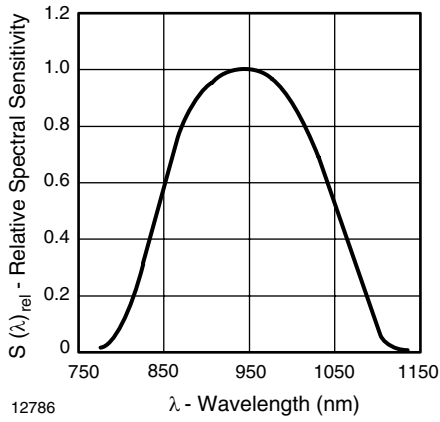


Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

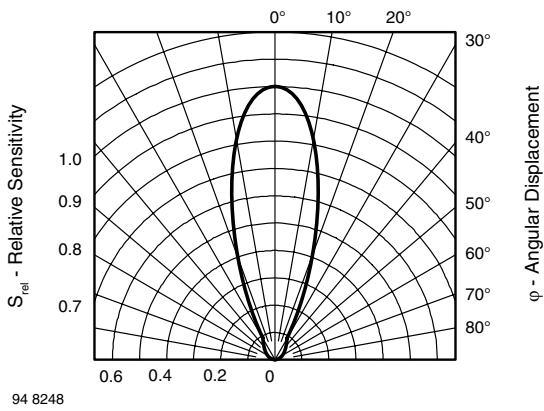


Fig. 12 - Relative Radiant Sensitivity vs. Angular Displacement

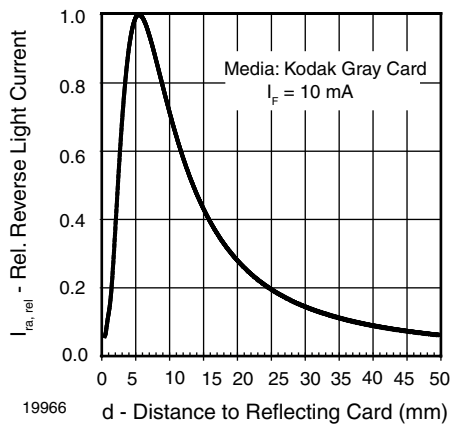


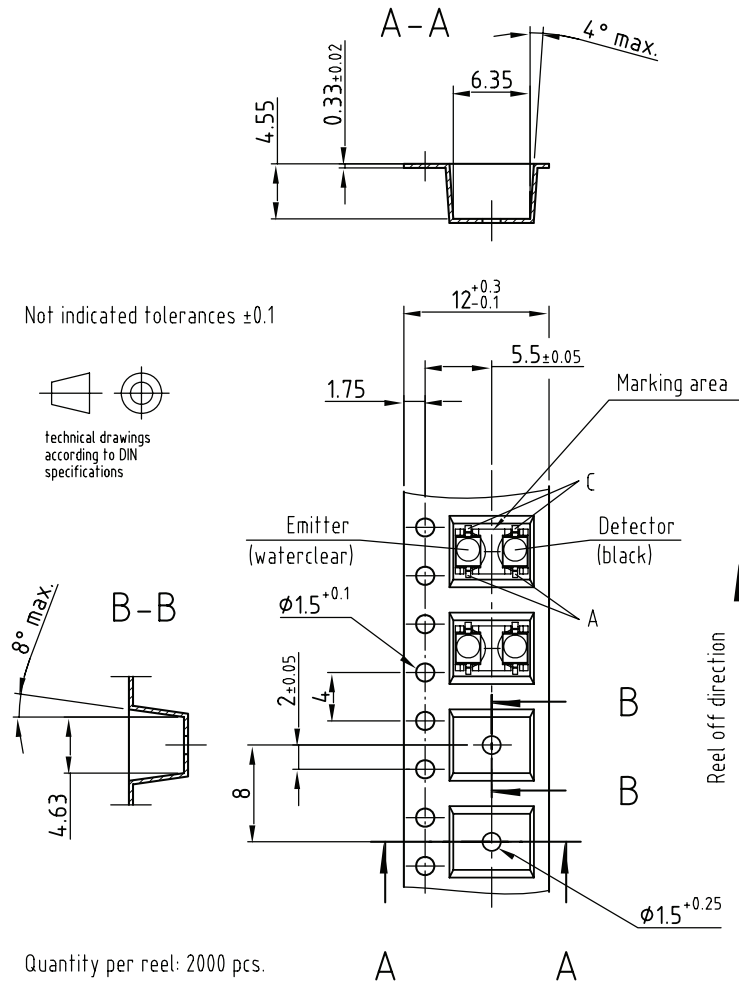
Fig. 13 - Relative Reverse Light Current vs. Distance

TCND5000



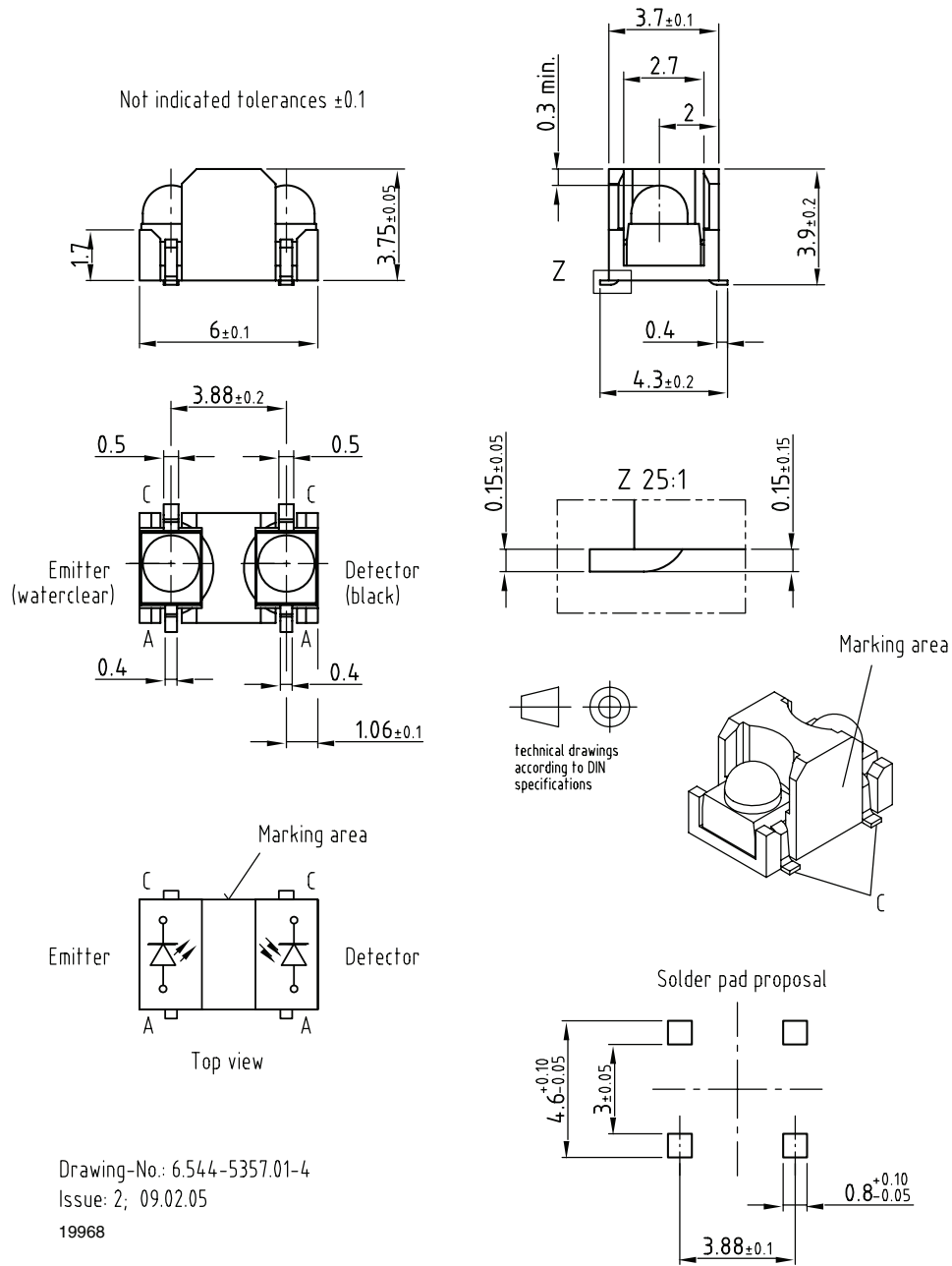
Vishay Semiconductors Reflective Optical Sensor with PIN Photodiode Output

TAPING Dimensions in millimeters



Material of Blister tape: PC black
Sealing of cavities with hot sealing cover tape,
C-Pak Type CP - 2010 AS (Thickness: 0.055 - 0.075mm; Base Material: Polyester)
Drawing-No.: 9.700-5281.01-4
Issue: 4; 10.02.05
18222

PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5357.01-4
 Issue: 2; 09.02.05
 19968

PRECAUTIONS FOR USE

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

2.1 Storage temperature and rel. humidity conditions are: 5 °C to 30 °C, RH 60 %

2.2 Floor life must not exceed 72 h, acc. to JEDEC level 4, J-STD-020.

Once the package is opened, the products should be used within 72 h. Otherwise, they should be kept in a damp proof box with desiccant.

Considering tape life, we suggest to use products within one year from production date.

2.3 If opened more than 72 h in an atmosphere 5 °C to 30 °C, RH 60 %, devices should be treated at 60 °C ± 5 °C for 15 h.

2.4 If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3

REFLOW SOLDER PROFILES

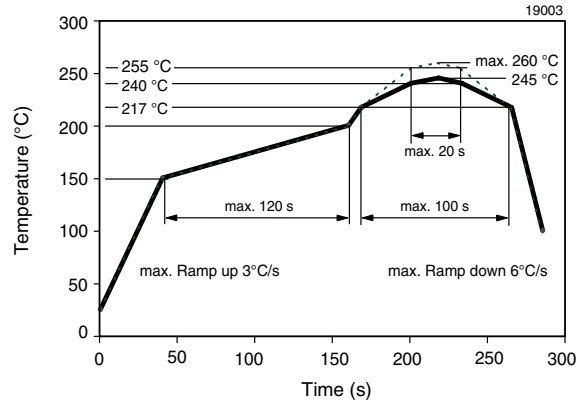


Fig. 14 - Lead (Pb)-Free Reflow Solder Profile

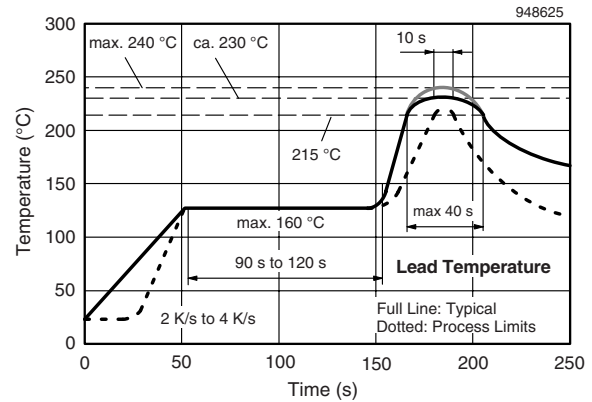


Fig. 15 - Lead Tin (SnPb) Reflow Solder Profile



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All product specifications and data are subject to change without notice.

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